

# APPLICATION NOTE

## **AN1890**

Using the SA7025 (RevA) and SA8025A  
for narrow band systems

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# Using the SA7025(RevA) and SA8025A for narrow band systems AN1890

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## INTRODUCTION

The SA7025 (RevA) and SA8025A are improved versions of the SA7025 and SA8025 suitable for narrow band systems like the America Digital Cellular System (IS-54) and Japan Personal Digital Cellular System (PDC). The new design improves the performance of the fractional spurs compensation, which is a by-product of the fractional-N divider. Complete design procedure and performance measurements on both the SA7025 (RevA) and SA8025A are included in this document.

The basics of the fractional-N PLL frequency synthesizers can be found in Philips Semiconductors application note AN1891, "SA8025 Fractional-N synthesizer for 2GHz band applications". AN1891 can be used in conjunction with this document for designing-in the SA7025, SA8025, SA7025 (RevA), and SA8025A.

## Fractional Spurs Compensation

The fractional-N divide ratio is achieved by changing the divide ratio between N and N+1. In lock condition, this technique will introduce an instantaneous phase error in the phase detector. This causes the VCO to generate unwanted spurs at the offset of the fractions of the comparison frequency.

On the new SA7025 (RevA) and SA8025A, the fractional compensation circuitry was re-designed to achieve better performance. Three improvements can be found on the SA7025 (RevA) and SA8025A due to this modification:

1. The CN range is much tighter. The CN values are the binary current setting factor for the charge pumps. These values may be varied across the desired frequency band (e.g. 25MHz) for fractional spurs compensation. For the SA7025/SA8025, the CN range is greater than 50 for narrow band systems (e.g. channel spacing,  $f_{CH}=30\text{kHz}$ ). For the new SA7025 (RevA)/SA8025A, this range is much tighter and a **fixed** CN value is usually good enough for all synthesized frequencies on the SA7025 (RevA)/SA8025A.
2. A more accurate calculation of the resistor  $R_F$ , which determines the amount of fractional compensation current. Eq. 1 gives an approximate value of  $I_{RF}$ .  $R_F$  can be calculated using Eq. 2, which is the same as the one for calculating resistor  $R_N$ . To obtain an optimum performance, the CN value can be adjusted accordingly.

$$I_{RF} = \frac{3 \cdot I_{RN} \cdot CN \cdot f_{XTAL}}{Q \cdot f_{VCO}} \quad (1)$$

$$R_F = \frac{V_{DDA} - 0.9 - 150 \cdot \sqrt{I_{RF}}}{I_{RF}} \quad (2)$$

3. Better performance over temperature. The variation of fractional spurs was minimized over the rated temperature range (-40 to +80°C).

## Compatibility Between the SA7025/SA8025 and SA7025 (RevA)/SA8025A

The SA7025/SA8025 and SA7025 (RevA)/SA8025A are pin-to-pin compatible and have exactly the same performance except for the fractional compensation section. When replacing the SA7025/SA8025 with SA7025 (RevA)/SA8025A, new values for CN and resistor  $R_F$  may have to be used. Users should calculate resistor  $R_F$  using Eq. 1 and 2 and experiment with it on the bench with the new  $R_F$  value.

## PLL Design Equations

$\delta$  : final frequency resolution after settling.

$$\delta = \frac{\text{frequency error after settling}}{\text{switching step}} \quad (3)$$

$t_{SW}$  : switching time (sec)

$f_N$  : natural frequency of the 2nd order system(Hz) ,

$$\omega_N = 2\pi f_N \text{ (rad/s)}$$

N : total divide ratio

$\xi$  : damping factor of the 2nd order system.

Typical value is 0.707.

$K_{VCO}$ : VCO gain (Hz/V) or  $2\pi \cdot$  VCO gain (rad/V)

$K_\phi$  : phase detector gain =  $I_{CP}/2\pi$  (A/rad)

$$\omega_N = \frac{-\ln(\delta \cdot \sqrt{1 - \xi^2})}{\xi \cdot t_{SW}} \quad (4)$$

$$C_1 = \frac{K_\phi \cdot K_{VCO}}{N\omega_N^2} \quad (5)$$

$$R_1 = 2 \cdot \xi \left( \frac{N}{K_\phi \cdot K_{VCO} \cdot C_1} \right)^{0.5} \quad (6)$$

$$C_2 \leq \frac{C_1}{10} \quad (7)$$

$$\omega = \frac{1}{C_3 \cdot R_2} \quad \omega \text{ should be at least 10 times larger than } \omega_N \quad (8)$$

Note: The unit of the factor  $K_\phi \cdot K_{VCO}$  is unity when all the variables are expressed in radians. Therefore, designers can simply multiply the charge pump output current ( $I_{CP}$ ) with the VCO gain in Hz/V to obtain this factor.

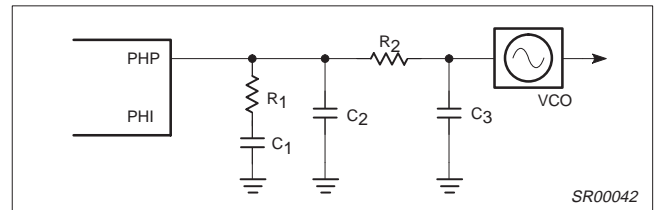


Figure 1. 3-Poles RC Lowpass Loop Filter

## SA7025 (RevA) Design Example

This section shows a design example using the SA7025 (RevA) for the IS-54. The system parameters are as follows:

VCO frequency ( $f_{VCO}$ ) = 913 to 938MHz

Channel spacing ( $f_{CH}$ ) = 30kHz

Comparison frequency ( $f_{COMP}$ ) =  $8 \cdot 30 \text{ kHz} = 240\text{kHz}$

Switching time ( $t_{SW}$ ) = 1.5ms

Switching step = 25MHz

Frequency error = within 1 kHz

VCO gain ( $K_{VCO}$ ) = 12MHz/V (measured), Murata MQE001-926

Reference Crystal ( $f_{REF}$ ) = 14.4MHz

### 1. Determine total divide ratio N

To synthesize channels from 913 to 938MHz with  $f_{COMP}=240\text{kHz}$ , N should be between 3804 and 3908. For the same loop components, a larger value of N yields lower natural frequency ( $f_N$ ). So, jumping from high-end to low-end (larger N) is slower than from low-end to

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high-end (smaller N). To ensure the same switching time from both directions, we use N=3908 for the worst case.

## 2. Determine $\omega_N$

$$\text{Using Eq. 3} \quad \delta = \frac{1000}{25e6} = 0.04e-3$$

Pick  $\xi = 0.707$  and use  $t_{SW} = 1.5\text{ms}$ .

$$\text{Using Eq. 4} \quad \omega_N = \frac{-\ln(0.04e-3 \cdot 0.707)}{0.707 \cdot 1500e-6} = 9830$$

## 3. Determine RN and $I_{CP}$

Pick RN = 51 k $\Omega$  and CN = 200.  $I_{RN}$  becomes 58 $\mu\text{A}$  when  $V_{DDA}=5\text{V}$ .

Using the PHP charge pump current equation

$$I_{CP} = 200 \left( \frac{58e-6}{32} \right) = 363\mu\text{A}$$

## 4. Determine $R_1$ , $C_1$ , and $C_2$

Using Eq. 5 with the  $2\pi$ 's from  $K_{VCO}$  (rad/V) and  $K_\phi$  (A/rad) cancel out

$$C_1 = 12e6 \left( \frac{363e-6}{3908 \cdot 9830^2} \right) = 11.5\text{nF}$$

Using Eq. 6

$$R_1 = 2 \cdot 0.707 \cdot \left( \frac{3908}{12e6 \cdot 363e-6 \cdot 11.5e-9} \right)^{0.5} = 13\text{k}\Omega$$

Using Eq. 7

$$C_2 = \frac{11.5e-9}{10} = 1.15\text{nF}$$

## 5. Determine $R_2$ and $C_3$

$R_2$  and  $C_3$  can help attenuate the comparison spurs at 240kHz offset.

$$\text{Using Eq. 8} \quad \omega = \frac{1}{R_2 \cdot C_3} \geq 10\omega_N$$

## 6. Determine RF

Crystal frequency ( $f_{TAL}$ ) = 14.4MHz

Mid VCO frequency ( $f_{VCO}$ ) = 926MHz

Q (fractional modulus) = 8

Using Eq. 1 and Eq. 2

$$I_{RF} = \frac{3 \cdot 58e-6 \cdot 200 \cdot 14.4e6}{8 \cdot 926e6} = 67.65\mu\text{A}$$

$$RF = \frac{5 - 0.9 - 150 \cdot \sqrt{67.65e-6}}{8 \cdot 926e6} = 43\text{k}\Omega$$

A minor adjustment of CN maybe required if optimum fractional spurs suppression is needed across the 25MHz band. The experimental results yielded the best spurious suppression at a value of RF=47k $\Omega$ .

Component values used on the SA7025(Rev A) demo board:

C31 = 10 nF

R23 = 13 k $\Omega$

C32 = 1 nF

R24 = 100 k $\Omega$

C33 = 18 pF

R21 = 47 k $\Omega$  (RF)

R22 = 51 k $\Omega$  (RN)

CN = 200

Strobe width = 260 $\mu\text{s}$

## Measurement Results of the SA7025 (RevA)

Figure 2 shows the measured close-in noise at 940.05MHz. The phase noise at 1kHz carrier offset is  $-49.4 - 10 \cdot \log(100) = -69.4$  dBc/Hz. Fractional spurs performance is shown in Figures 3 to 6. The worst case spurs occur when NF=1 and NF=7 are less than -60dBc. Spurs at the alternate channel, the 60kHz carrier offset required by the IS-54, are totally suppressed. Figures 7 and 8 show the measured switching times. These results show that the PLL can jump a 25MHz step in less than 1.5ms from both directions.

Table 1 shows the difference in performance between the SA7025 and SA7025 (RevA) using the same demoboard. Unless otherwise mentioned, CN=200, RN=51k $\Omega$ , RF=47k $\Omega$ .

## Speed-up Design for Achieving Better Close-in Noise

Better close-in noise can be achieved at the expense of operational current. The PHP charge pumps on the SA7025 (RevA) and SA8025A are both capable of delivering more than 1.5mA in the speed-up mode. To stay in this mode, the STROBE signal has to be kept high after the programming word 'A' is sent. The CL register sets the amount of charge pump current which is either 3 times (CL=0), 5 times (CL=1), or 9 times (CL=2) higher than the current in normal mode. Assume that we want to modify the previous design and use speed-up with CL=1. This implies that the charge pump output current becomes  $5 \cdot 363\mu\text{A} = 1.8\text{mA}$ . In order to maintain the same natural frequency, the value of C31 and C32 is increased by a factor of 5 and R23 is decreased by the same factor of 5. Therefore, the new values used on the demo board are:

C31 = 100nF in parallel with 100nF

C32 = 4.7nF

R23 = 2.4k $\Omega$

Figure 9 compares the close-in phase noise of the two designs with the same natural frequency. The bottom trace has a 4dB improvement in the close-in noise when speed-up mode (higher current) is used. Since the phase noise beyond the loop bandwidth is solely determined by the VCO phase noise, two traces start to merge together at about 5kHz offset.

## SA8025A Design Example

This section shows a design example using the SA8025A for the Personal Digital System (PDC1500), a narrow band system. The design procedure is the same as the previous section. The system parameters are as follows:

VCO frequency ( $f_{VCO}$ ) = 1607 to 1631 MHz

Channel spacing ( $f_{CH}$ ) = 25kHz

Comparison frequency ( $f_{COMP}$ ) =  $8 \cdot 25\text{kHz} = 200\text{kHz}$

Switching time ( $t_{SW}$ ) = 1.5ms

Switching step = 24MHz

Frequency error = within 1kHz

VCO gain ( $K_{VCO}$ ) = 24 MHz/V (measured), Murata MQE060-1619

Reference Crystal ( $f_{REF}$ ) = 19.2MHz

## Using the SA7025(RevA) and SA8025A for narrow band systems

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**Table 1. Performance Comparison: SA7025 to SA7025 (Rev A)**

	SA7025	SA7025 (Rev A)	Figure
Fractional spurs (dBc) @30kHz, VCO=912.99MHz	-57.6 (CN=200, RF=2MΩ)	-63.6	3
Fractional spurs (dBc) @60kHz, VCO=912.99MHz	not present (CN=200, RF=2MΩ)	not present	3
Fractional spurs (dBc) @30kHz, VCO=939.87MHz	-63.5 (CN=100, RF=2MΩ)	-63.9	5
Fractional spurs (dBc) @60kHz, VCO=939.87MHz	not present (CN=100, RF=2MΩ)	not present	5
Close-in noise (dBc/Hz) @1kHz, VCO=1631.025MHz	-69	-69	2
I <sub>TOTAL</sub> (mA) for the demo board	21.2	21.2	
Switching time (ms)	<1.5	<1.5	7, 8

**1. Determine total divide ratio N**

$$N = \frac{1631\text{MHz}}{200\text{kHz}} = 8155$$

**2. Determine  $\omega_N$** 

Using Eq. 3  $\delta = \frac{1000}{24e6} = 0.042e-3$

Pick  $\xi = 0.707$  and use  $t_{SW} = 1.5\text{ms}$ .

Using Eq. 4  $\omega_N = \frac{-\ln(0.042e-3 \cdot 0.707)}{0.707 \cdot 1500e-6} = 9830$

**3. Determine  $R_N$  and  $I_{CP}$** 

Pick  $R_N = 51\text{k}\Omega$  and  $C_N = 200$ .  $I_{RN}$  becomes  $58\mu\text{A}$  when  $V_{DDA}=5\text{V}$ .

Using the PHP charge pump current equation

$$I_{CP} = 200 \left( \frac{58e-6}{32} \right) = 363\mu\text{A}$$

**4. Determine  $R_1$ ,  $C_1$ , and  $C_2$** 

Using Eq. 5

$$C_1 = 24e6 \left( \frac{363e-6}{8155 \cdot 9830^2} \right) = 11.1\text{nF}$$

Using Eq. 6

$$R_1 = 2 \cdot 0.707 \cdot \sqrt{\left( \frac{8155}{24e6 \cdot 363e-6 \cdot 11.1e-9} \right)} = 13\text{k}\Omega$$

Using Eq. 7

$$C_2 = \frac{11.1e-9}{10} = 1.1\text{nF}$$

**5. Determine  $R_2$  and  $C_3$** 

$R_2$  and  $C_3$  can help attenuate the comparison spurs at 200kHz offset.

Using Eq. 8

$$\omega = \frac{1}{R_2 \cdot C_3} \geq 10\omega_N$$

Pick  $R_2 = 360\text{k}\Omega$ , then  $C_3 = 18\text{pF}$ .

**6. Determine RF**

Crystal frequency ( $f_{XTAL}$ ) = 19.2MHz  
 Mid VCO frequency ( $f_{VCO}$ ) = 1619MHz  
 Q (fractional modulus) = 8  
 Using Eq. 1 and Eq. 2

$$I_{RF} = \frac{3 \cdot 58e-6 \cdot 200 \cdot 14.4e6}{8 \cdot 926e6} = 67.65\mu\text{A}$$

$$RF = \frac{5 - 0.9 - 150 \cdot \sqrt{67.65e-6}}{8 \cdot 926e6} = 43\text{k}\Omega$$

Minor adjustment of CN is required if optimum fractional spurs suppression is needed.

Component values used on the demo board:

C31 = 10nF  
 R23 = 13kΩ  
 C32 = 1nF  
 R24 = 360kΩ  
 C33 = 18pF  
 R21 = 56kΩ (RF)  
 R22 = 51kΩ (RN)  
 CN = 200  
 Strobe width = 260μs

**Measurement Results of the SA8025A**

Close-in phase noise spectrum is shown in the Figure 10. At 1kHz carrier offset, the phase noise is  $-45.3 - 10 \cdot \log(100) = -65.3$  dBc/Hz. The 3dB loop bandwidth is 3kHz, which is about twice as much as the loop natural frequency ( $f_N$ ). Fractional spurs performance is shown in Figure 11 to 14. Worst case spurs when  $NF=1$  and  $NF=7$  for the low and high bands are all less than -59dBc. Spurs at 50kHz carrier offset, the alternate channel for PDC1500, were totally suppressed. Switching time measurements are shown in Figure 15 and 16. The PLL can reach the desired frequency for a 24MHz jump in less than 1.5ms from both directions.

Table 2 shows the difference in performance between the SA8025 and SA8025A using the same demoboard. Unless otherwise mentioned, CN=200, RN=51kΩ, RF=56kΩ.

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**Table 2. Performance Comparison: SA8025 to SA8025A**

	SA8025	SA8025A	Figure
Fractional spurs (dBc) @25kHz, VCO=1606.625MHz	-41.5 (CN=250, RF=560kΩ)	-60.6	11
Fractional spurs (dBc) @50kHz, VCO=1606.625MHz	not present (CN=250, RF=560kΩ)	not present	11
Fractional spurs (dBc) @25kHz, VCO=1631.025MHz	-59.0 (CN=200, RF=560kΩ)	-59.5	13
Fractional spurs (dBc) @50kHz, VCO=1631.025MHz	not present (CN=200, RF=560kΩ)	not present	13
Close-in noise (dBc/Hz) @1kHz, VCO=1631.025MHz	-65	-65	10
I <sub>TOTAL</sub> (mA) for the demo board	28.3	28.3	
Switching time (ms)	<1.5	<1.5	15, 16

## SA8025A for the PHS System

Philips Semiconductors applications note AN1891, "Using the SA8025 in 2GHz band applications", shows a design for the PHS system based on the SA8025. If the SA8025A is used in the same design, only RF needs to be changed.

Crystal frequency (f<sub>XTAL</sub>) = 19.2MHz  
 Mid VCO frequency (f<sub>VCO</sub>) = 1665MHz  
 Q (fractional modulus) = 8

I<sub>RN</sub> = 80μA  
 CN = 100

Using Eq. 1 and Eq. 2

$$I_{RF} = \frac{3 \cdot 80e-6 \cdot 100 \cdot 19.2e6}{8 \cdot 1865e6} = 34.6\mu A$$

$$RF = \frac{3 - 0.9 - 150 \cdot \sqrt{34.6e-6}}{34.6e-6} = 35.2k\Omega$$

On the demo board, RF=36kΩ was used. The measured fractional spurs when NF=1 and NF=7 are both better than -70dBc.

Table 3 summarizes the components change for the SA7025/SA8025 and the SA7025 (RevA)/SA8025A demo boards.

**Table 3. Summary of Component Changes**

Component	SA7025	SA7025 (Rev A)	SA8025	SA8025A
R21	560kΩ	47kΩ	560kΩ	36kΩ
R22	33kΩ	51kΩ	10kΩ	10kΩ
R23	24kΩ	13kΩ	10kΩ	10kΩ
R24	22kΩ	100kΩ	18kΩ	18kΩ
R25	22kΩ	0Ω	0Ω	0Ω
C30	330pF	NL	NL	NL
C31	3.3nF	10nF	3.9nF	3.9nF
C32	220pF	1nF	390pF	390pF
C33	220pF	18pF	150pF	150pF
C34	100pF	NL	NL	NL
NL = Not Loaded				

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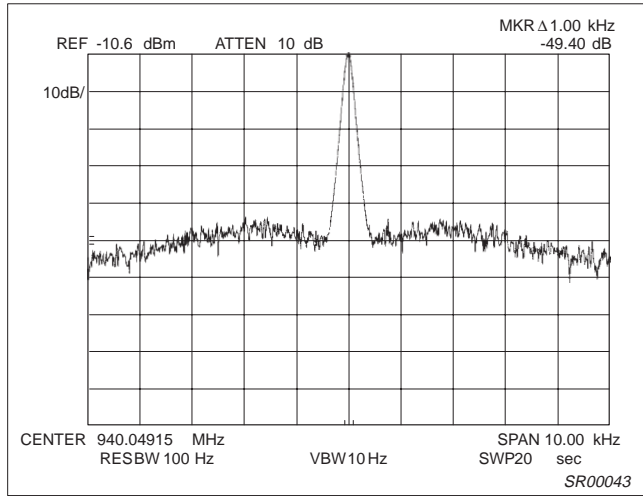


Figure 2. Close-In Noise at 940.05MHz

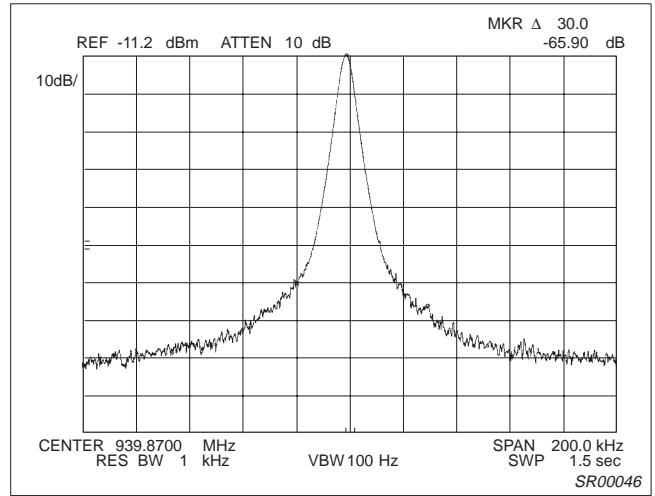


Figure 5. Fractional Spurs, ( $f_{VCO} = 939.87\text{MHz}$ ;  $NF = 1$ )

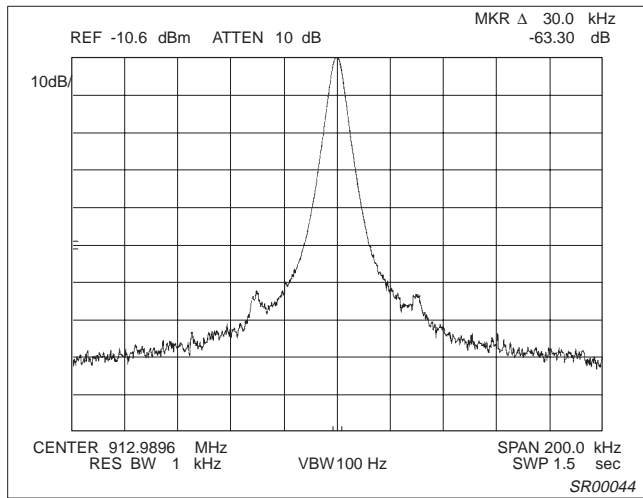


Figure 3. Fractional Spurs, ( $f_{VCO} = 912.99\text{MHz}$ ;  $NF = 1$ )

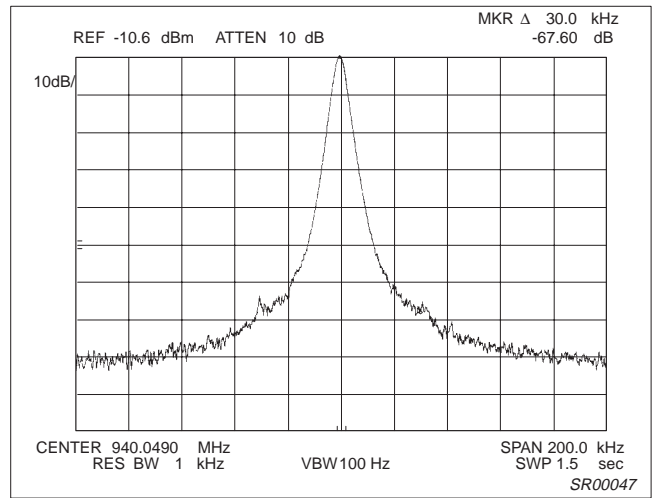


Figure 6. Fractional Spurs, ( $f_{VCO} = 940.05\text{MHz}$ ;  $NF = 7$ )

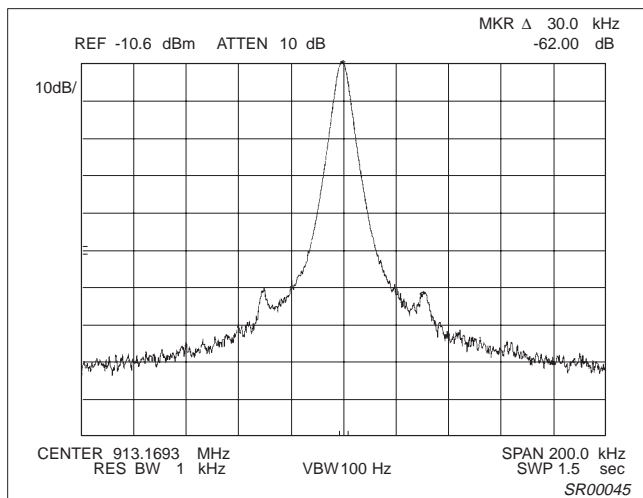


Figure 4. Fractional Spurs, ( $f_{VCO} = 913.17\text{MHz}$ ;  $NF = 7$ )

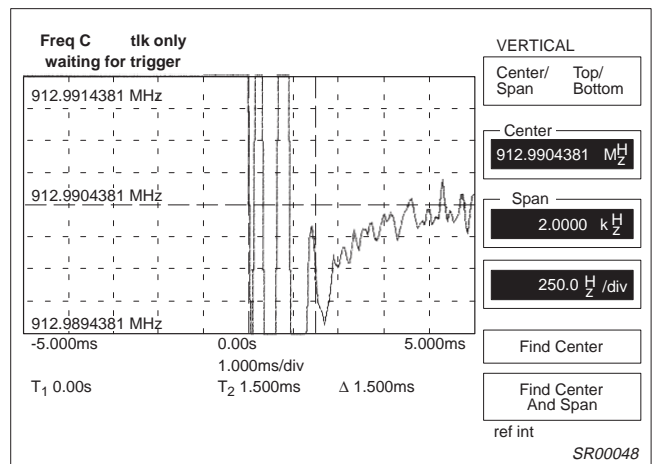
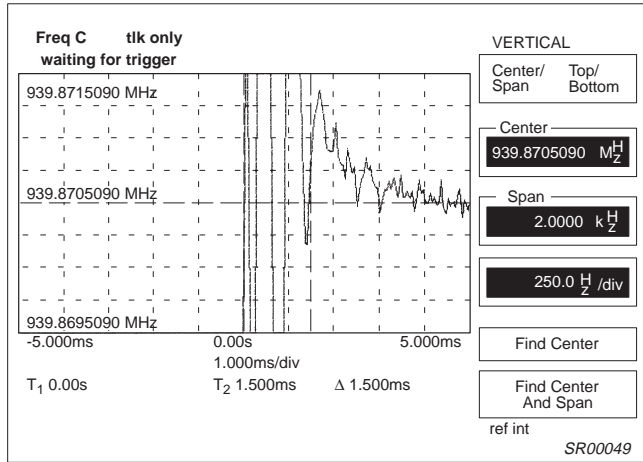


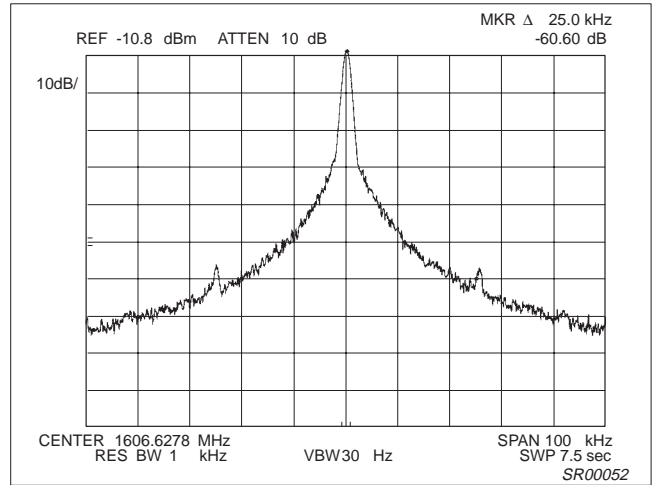
Figure 7. Switching Time (939.87 to 912.99MHz Step to Within 1kHz)

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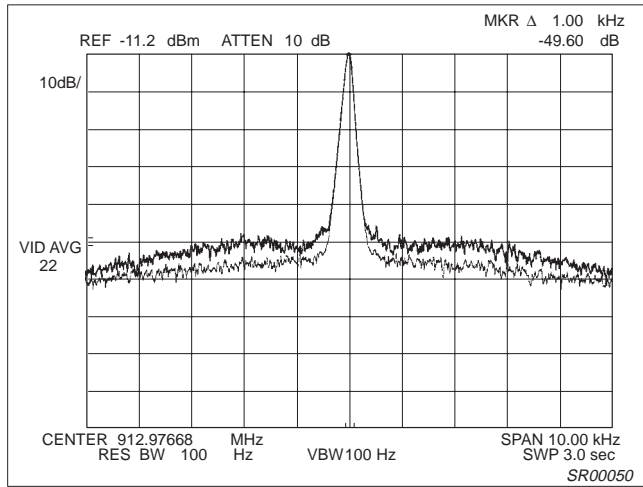
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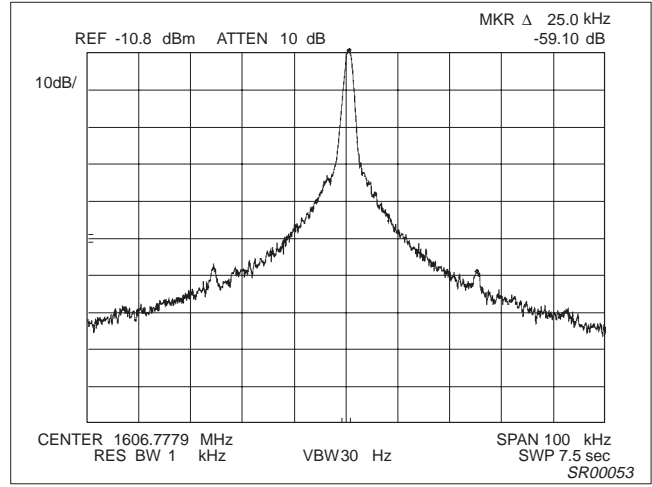
**Figure 8. Switching Time (912.99 to 939.87MHz Step to Within 1kHz)**



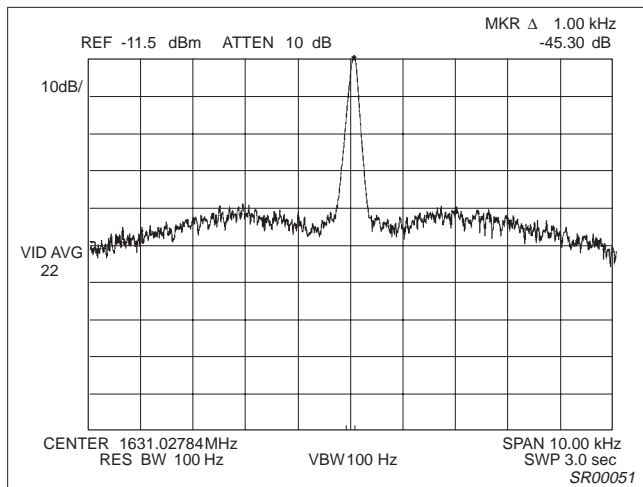
**Figure 11. Fractional Spurs, (f<sub>VCO</sub> = 1606.625MHz; NF = 1)**



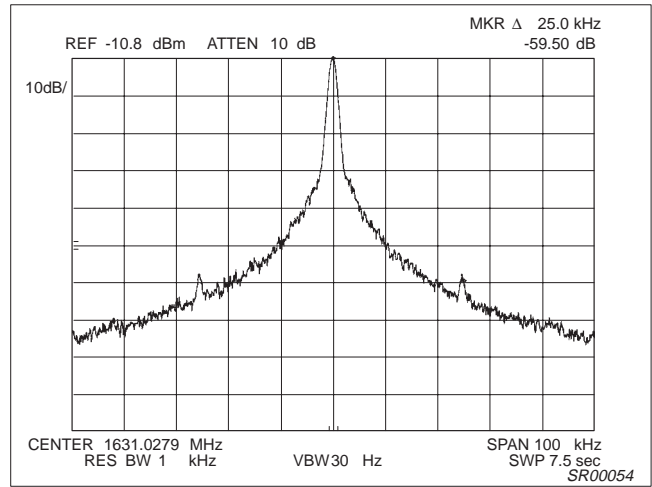
**Figure 9. Close-In Phase Noise When CL = 1**



**Figure 12. Fractional Spurs, (f<sub>VCO</sub> = 1606.775MHz; NF = 7)**



**Figure 10. Close-In Phase Noise at 1631.025MHz**



**Figure 13. Fractional Spurs, (f<sub>VCO</sub> = 1606.775MHz; NF = 7)**

# Using the SA7025(RevA) and SA8025A for narrow band systems

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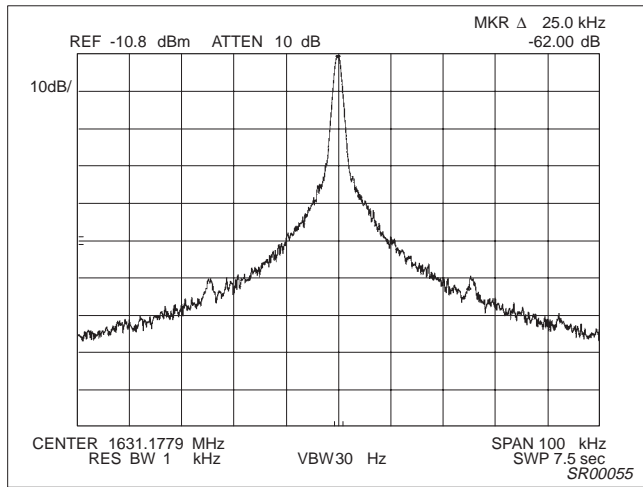


Figure 14. Fractional Spurs, ( $f_{VCO} = 1631.175\text{MHz}$ ;  $NF = 7$ )

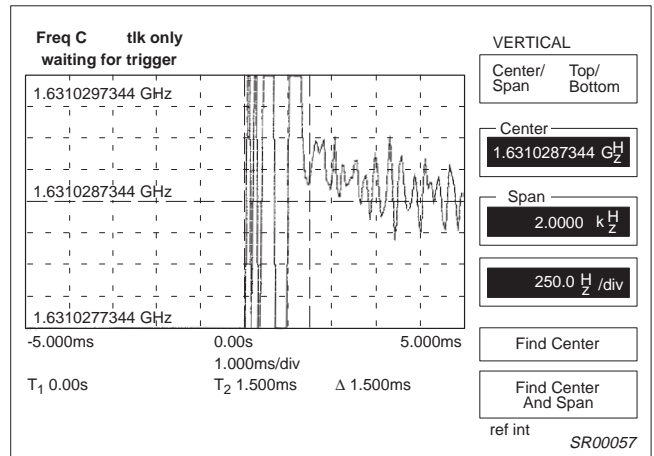


Figure 16. Switching Time  
(1606.625 to 1631.025MHz Step to Within 1kHz)

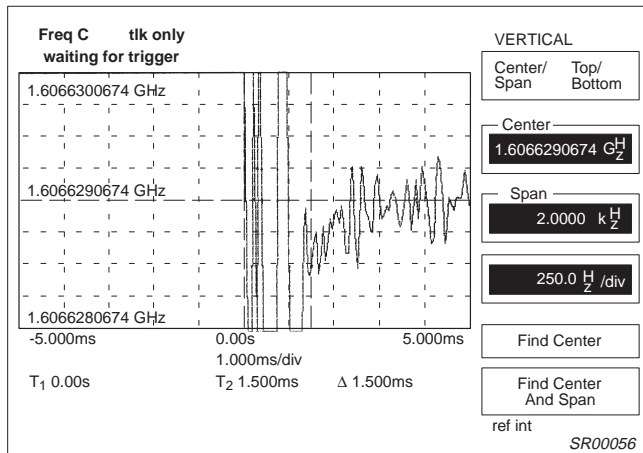


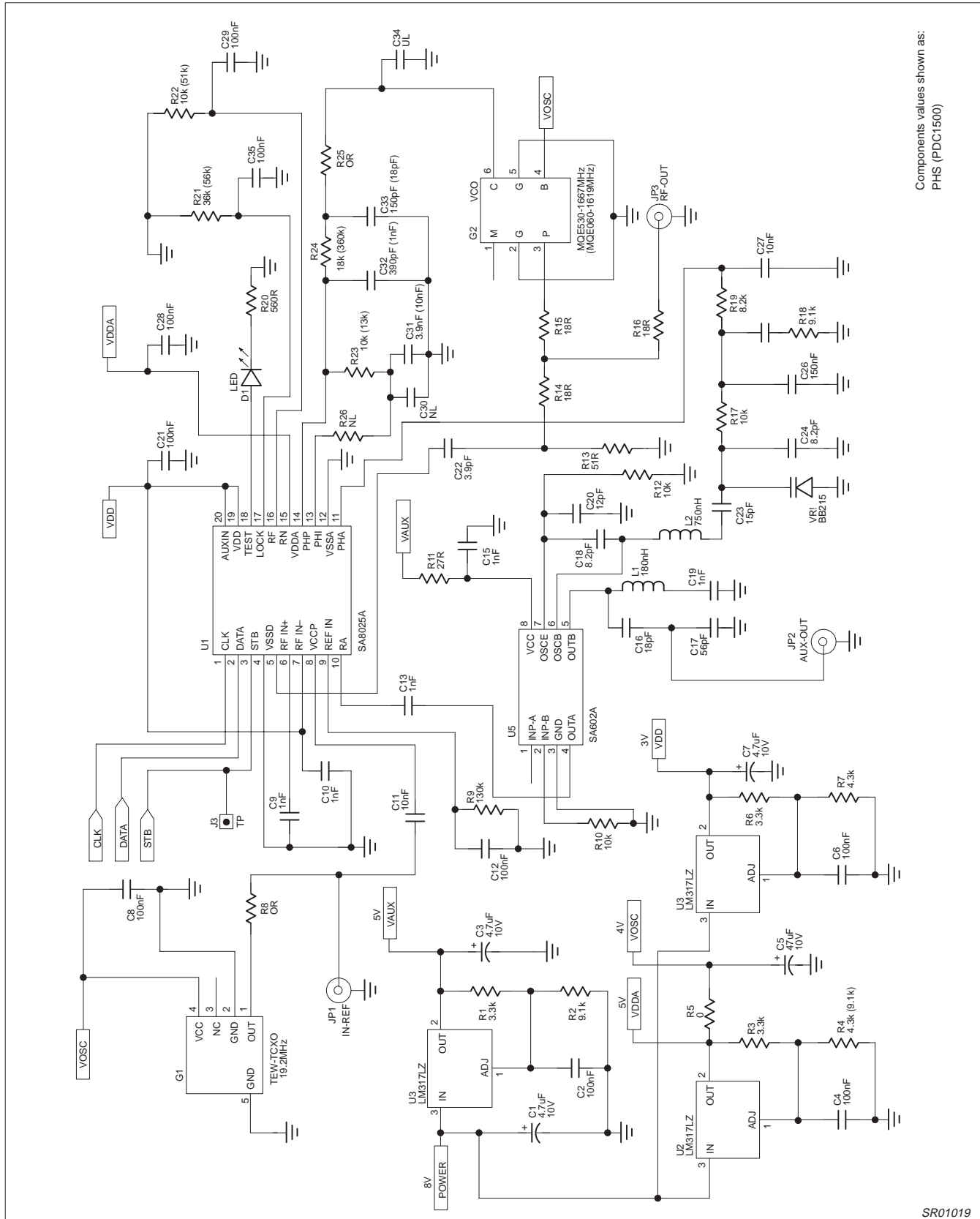
Figure 15. Switching Time  
(1631.025 to 1606.625MHz Step to Within 1kHz)





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Components values shown as:  
PHS (PDC1500)

SR01019

Figure 18. SA8025ADK Application Circuit

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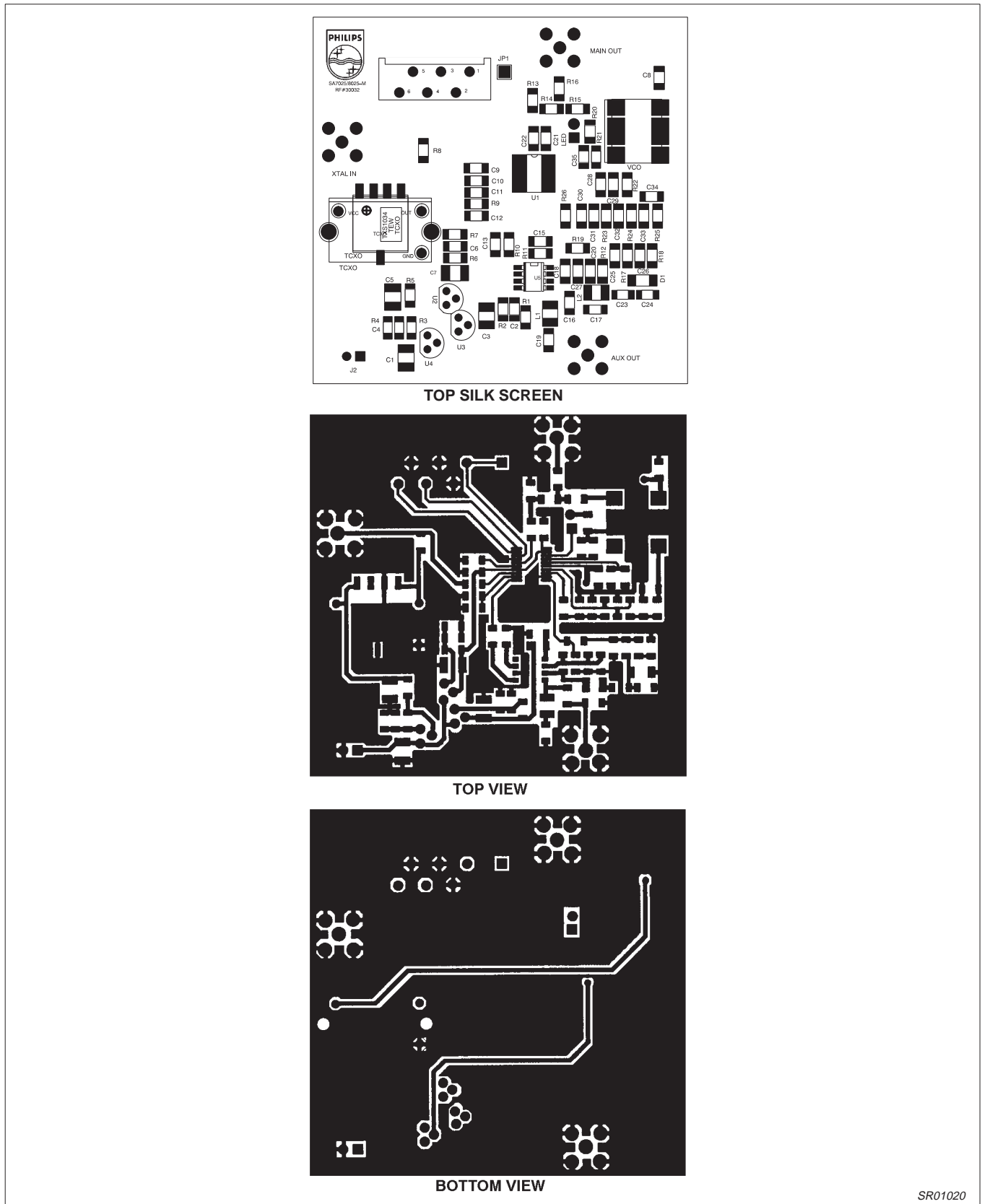


Figure 19. SA8025ADK Demoboard Layout (NOT ACTUAL SIZE)

SR01020

## Using the SA7025(RevA) and SA8025A for narrow band systems

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Table 4. Customer Application Component List for SA7025DK

Qty.	Value	Volt	Part Reference	Part Description	Vendor	Mfg	Part Number
<b>Surface Mount Capacitors</b>							
1	3.9pF	50V	C22	Cap. cer. 1206 NPO $\pm 0.5\text{pF}$	Garrett	Rohm	MCH315A3R9CK
2	8.2pF	50V	C24, C18	Cap. cer. 1206 NPO $\pm 0.5\text{pF}$	Garrett	Rohm	MCH315A8R2CK
1	12pF	50V	C20	Cap. cer. 1206 NPO $\pm 5\%$	Garrett	Rohm	MCH315A120JK
1	15pF	50V	C23	Cap. cer. 1206 NPO $\pm 5\%$	Garrett	Rohm	MCH315A150JK
2	18pF	50V	C16, C33	Cap. cer. 1206 NPO $\pm 5\%$	Garrett	Rohm	MCH315A180JK
1	56pF	50V	C17	Cap. cer. 1206 NPO $\pm 5\%$	Garrett	Rohm	MCH315A560JK
6	1000pF	50V	C9, C10, C13, C15, C19, C32	Cap. cer. X7R $\pm 10\%$	Garrett	Rohm	MCH315A102JP
4	0.01 $\mu\text{F}$	50V	C11, C25, C27, C31	Cap. cer. X7R $\pm 10\%$	Garrett	Rohm	MCH315C103KK
9	0.1 $\mu\text{F}$	50V	C2, C4, C6, C8, C12, C21, C28, C29, C35	Cap. cer. X7R $\pm 10\%$	Garrett	Rohm	MCH315C104KP
1	0.15 $\mu\text{F}$	16V	C26	Cap. cer. X7R $\pm 10\%$	Garrett	Rohm	MCH315C154KP
4	4.7 $\mu\text{F}$	10V	C1, C3, C5, C7	Tant. chip cap. A 3216 $\pm 10\%$	Garrett	Philips	49MC475B010KOAS
<b>Surface Mount Resistors</b>							
2	0 $\Omega$	50V	R8, R25	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW000E
3	18 $\Omega$	50V	R14, R15, R16	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW180E
1	27 $\Omega$	50V	R11	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW270E
1	51 $\Omega$	50V	R13	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW510E
1	100 $\Omega$	50V	R5	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW101E
1	560 $\Omega$	50V	R20	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW561E
3	3.3k $\Omega$	50V	R1, R3, R6	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW332E
1	4.7k $\Omega$	50V	R7	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW472E
1	8.2k $\Omega$	50V	R19	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW822E
3	9.1k $\Omega$	50V	R2, R18, R4	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW912E
3	10k $\Omega$	50V	R10, R12, R17	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW103E
1	13k $\Omega$	50V	R23	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW133E
1	47k $\Omega$	50V	R21	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW473E
1	51k $\Omega$	50V	R22	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW513E
1	100k $\Omega$	50V	R24	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW104E
1	130k $\Omega$	50V	R9	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW134E
1	560k $\Omega$	50V	R21	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW564E
<b>Surface Mount Diodes</b>							
1			VR1 (Varactor)	Variable capacitance SMD diode	Digikey	Philips	BB215
1			D1	SM Led	Digikey		
<b>Surface Mount Inductors</b>							
1	0.18 $\mu\text{H}$		L1	Chip inductor 1008 $\pm 10\%$	Coilcraft	Coilcraft	1008CS-181XKBB
1	0.75 $\mu\text{H}$		L2	Chip inductor 1008 $\pm 10\%$	Coilcraft	Coilcraft	1008CS-751XKBB
<b>Voltage Regulators</b>							
3	100mA		U1, U2, U3	Voltage regulator	Digikey	National	LM317LZ
<b>TCXO</b>							
1	14.4MHz		G1	Temp. controlled crystal osc.	TEW	TEW	TXS0924M-14.4MHz
<b>VCO</b>							
1	926MHz		G2	Voltage controlled osc.	Murata	Murata Erie	MQE001-926
<b>Surface Mount Integrated Circuits</b>							
1			U4	1GHz Fractional-N Synthesizer	Philips	Philips	SA7025DK
1			U5	Double Balanced Mixer Oscillator	Philips	Philips	SA602A
<b>Miscellaneous</b>							
3			JP1, JP2, JP3	SMA right angle jack receptacle	Newark	EF Johnson	142-0701-301
1			J1	Male 6-pins connector	STOCKO	STOCKO	MKS1956-6-0-606
1			J2	Male 2-pins connector	STOCKO	STOCKO	MKS1851-6-0-202
1			J3	Test point	Digikey	3M	929647-36
1				Printed circuit board	Philips	Philips	SA7025/8025-M
<b>75 Total Parts</b>							

## Using the SA7025(RevA) and SA8025A for narrow band systems

AN1890

Table 5. Customer Application Component List for SA8025ADK

Qty.	Part Value	Volt	Part Reference	Part Description	Vendor	Mfg	Part Number
<b>Surface Mount Capacitors</b>							
1	3.9pF	50V	C22	Cap. cer. 1206 NPO $\pm 0.5\text{pF}$	Garrett	Rohm	MCH315A3R9CK
2	8.2pF	50V	C24, C18	Cap. cer. 1206 NPO $\pm 0.5\text{pF}$	Garrett	Rohm	MCH315A8R2CK
1	12pF	50V	C20	Cap. cer. 1206 NPO $\pm 5\%$	Garrett	Rohm	MCH315A120JK
1	15pF	50V	C23	Cap. cer. 1206 NPO $\pm 5\%$	Garrett	Rohm	MCH315A150JK
1	18pF	50V	C16	Cap. cer. 1206 NPO $\pm 5\%$	Garrett	Rohm	MCH315A180JK
1	56pF	50V	C17	Cap. cer. 1206 NPO $\pm 5\%$	Garrett	Rohm	MCH315A560JK
1	150pF	50V	C33	Cap. cer. 1206 NPO $\pm 5\%$	Garrett	Rohm	MCH315A151JK
1	390pF	50V	C32	Cap. cer. 1206 NPO $\pm 5\%$	Garrett	Rohm	MCH315A391JK
5	1000pF	50V	C9, C10, C13, C15, C19	Cap. cer. X7R $\pm 10\%$	Garrett	Rohm	MCH315A102JP
1	3900pF	50V	C31	Cap. cer. X7R $\pm 10\%$	Garrett	Rohm	MCH315C392KK
3	0.01 $\mu\text{F}$	50V	C11, C25, C27	Cap. cer. X7R $\pm 10\%$	Garrett	Rohm	MCH315C103KK
9	0.1 $\mu\text{F}$	50V	C2, C4, C6, C8, C12, C21, C28, C29, C35	Cap. cer. X7R $\pm 10\%$	Garrett	Rohm	MCH315C104KP
1	0.15 $\mu\text{F}$	16V	C26	Cap. cer. X7R $\pm 10\%$	Garrett	Rohm	MCH315C154KP
4	4.7 $\mu\text{F}$	10V	C1, C3, C5, C7	Tant. chip cap. A 3216 $\pm 10\%$	Garrett	Philips	49MC475B010KOAS
<b>Surface Mount Resistors</b>							
3	0 $\Omega$	50V	R5, R8, R25	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW000E
3	18 $\Omega$	50V	R14, R15, R16	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW180E
1	27 $\Omega$	50V	R11	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW270E
1	51 $\Omega$	50V	R13	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW510E
1	560 $\Omega$	50V	R20	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW561E
3	3.3k $\Omega$	50V	R1, R3, R6	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW332E
2	4.3k $\Omega$	50V	R4, R7	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW432E
1	8.2k $\Omega$	50V	R19	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW822E
2	9.1k $\Omega$	50V	R2, R18	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW912E
5	10k $\Omega$	50V	R10, R12, R17, R22, R23	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW103E
1	18k $\Omega$	50V	R24	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW183E
1	36k $\Omega$	50V	R21	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW364E
1	130k $\Omega$	50V	R9	Res. chip 1206 1/8W $\pm 5\%$	Garrett	Rohm	MCR18JW134E
<b>Surface Mount Diodes</b>							
1			VR1 (Varactor)	Variable capacitance SMD diode	Digikey	Philips	BB215
1			D1	SM Led	Digikey		
<b>Surface Mount Inductors</b>							
1	0.18 $\mu\text{H}$		L1	Chip inductor 1008 $\pm 10\%$	Coilcraft	Coilcraft	1008CS-181XKBB
1	0.75 $\mu\text{H}$		L2	Chip inductor 1008 $\pm 10\%$	Coilcraft	Coilcraft	1008CS-751XKBB
<b>Voltage Regulators</b>							
3	100mA		U1, U2, U3	Voltage regulator	Digikey	National	LM317LZ
<b>TCXO</b>							
1	19.2MHz		G1	Temp. controlled crystal osc.	TEW	TEW	TXS1034N-19.2MHz
<b>VCO</b>							
1	1667MHz		G2	Voltage controlled osc.	Murata	Murata Erie	MQE530-1667
<b>Surface Mount Integrated Circuits</b>							
1			U4	2GHz Fractional-N Synthesizer	Philips	Philips	SA8025ADK
1			U5	Double Balanced Mixer Oscillator	Philips	Philips	SA602A
<b>Miscellaneous</b>							
3			JP1, JP2, JP3	SMA right angle jack receptacle	Newark	EF Johnson	142-0701-301
1			J1	Male 6-pins connector	STOCKO	STOCKO	MKS1956-6-0-606
1			J2	Male 2-pins connector	STOCKO	STOCKO	MKS1851-6-0-202
1			T3	Test point	Digikey	3M	929647-36
1				Printed circuit board	Philips	Philips	SA7025/8025-M
<b>75 Total Parts</b>							